



# M0220MD-202MDAR1-3

# **Dot-matrix Character Vacuum Fluorescent Display Module**

M- VFD Module

0220- 2 Lines x 20 Characters

M- Model D- Dot-Matrix

202MDA- Character Size = 3.85mm x 8.95mm

R- RoHS Compliant
1-3 M68 Parallel Interface

### Newhaven Display International, Inc.

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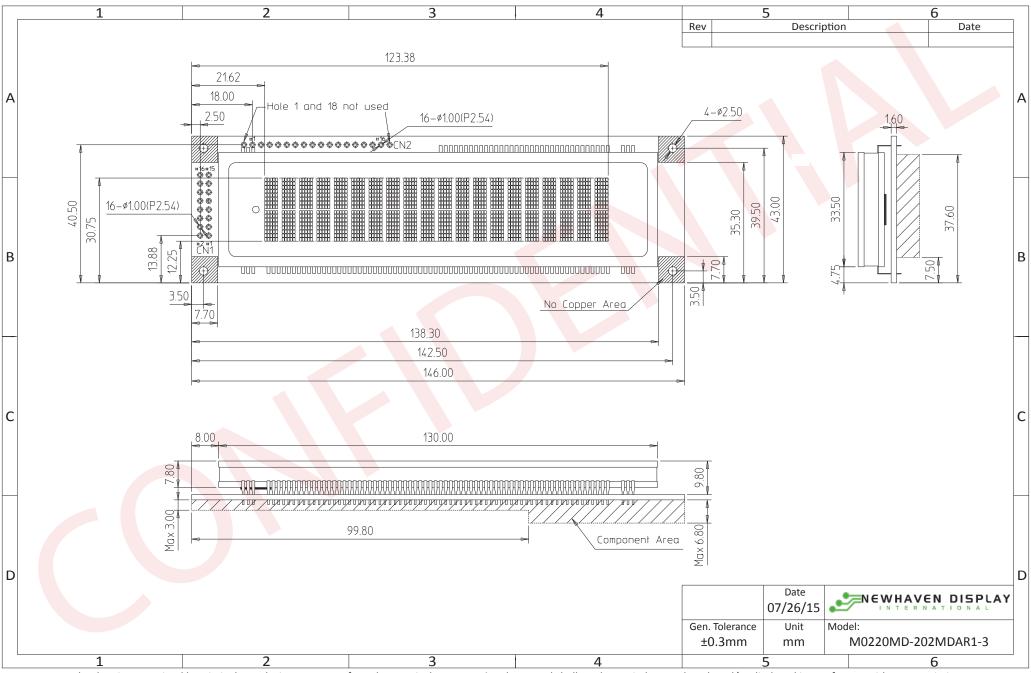
**Document Revision History** 

Revision	Date	Description	Changed by
0	3/21/2005	Initial Release	-
1	9/21/2009	Updated Driver version, modified VF glass pins	CL
2	12/4/2009	Reduce pixel size to increase brightness and lifetime	CL
3	1/26/2011	Storage temperature updated	JT
4	7/26/15	Module redesigned	AK

#### **Functions and Features**

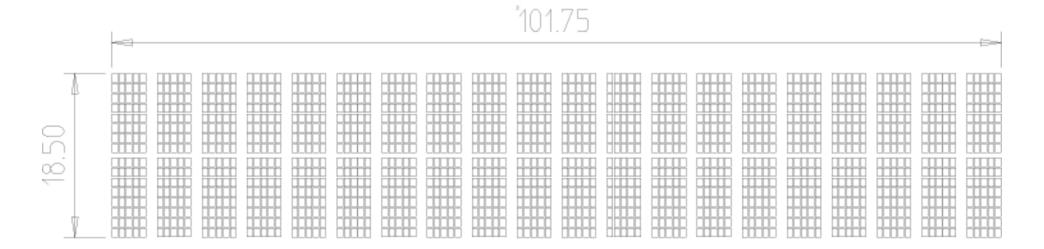
- 2 lines x 20 characters
- Built-in controller
- Built-in VF AC power supply
- 5.0V power supply
- 5x8 dots with cursor
- Parallel interface (serial interface selectable by onboard jumpers)
- Display color: x = 0.250, y = 0.439 (Green)

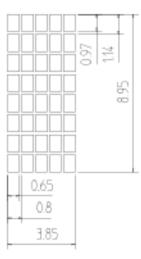
## **Mechanical Drawing**



The drawing contained herein is the exclusive property of Newhaven Display International, Inc. and shall not be copied, reproduced, and/or disclosed in any format without permission.

#### **Pattern Detail**





# **Pin Description**

### Parallel Interface (Default):

Pin No.	Symbol	External	Function Description
		Connection	
1	VSS	Power Supply	Ground
2	VDD	Power Supply	Supply Voltage for logic (+5.0V)
3	NC (/RST)	- (MPU)	No Connect (if JP2 is short, PIN3 = Active LOW reset signal)
4	RS	MPU	Register Select signal RS=1: DATA RS=0: COMMAND
5	R/W	MPU	Read/Write select signal R/W=1: Read, R/W=0: Write
6	E	MPU	Operation Enable signal. Falling Edge Triggered
7-10	DB0 – DB3	MPU	Four low order bi-directional three-state data bus lines.
			These four are not used during 4-bit operation
11-14	DB4 – DB7	MPU	Four high order bi-directional three-state data bus lines.

Recommended LCD connector: 2.54mm pitch pins

#### **Serial Interface:**

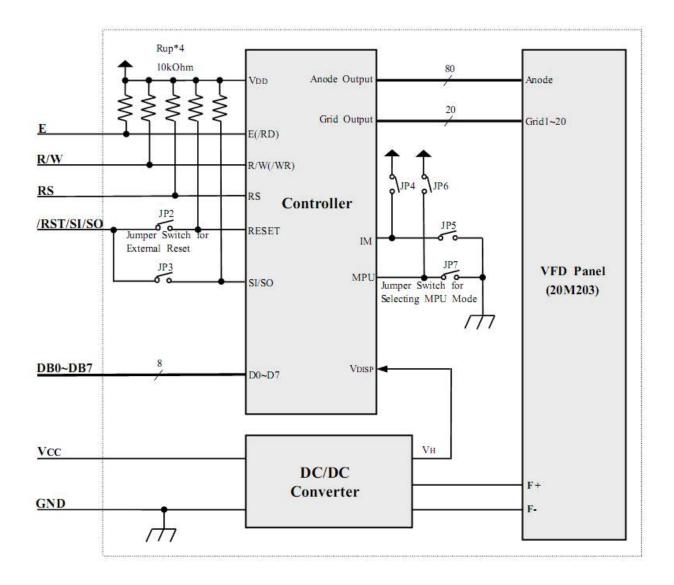
Pin No.	Symbol	External	Function Description
		Connection	
1	VSS	Power Supply	Ground
2	VDD	Power Supply	Supply Voltage for logic (+5.0V)
3	SI/SO	MPU	Serial Data In/Out signal
4	STB	MPU	Serial Strobe signal
5	NC	-	No Connect
6	SCK	MPU	Serial Clock signal
7-16	NC	-	No Connect

# **Jumper Settings**

Mode	JP2	JP3	JP4	JP5	JP6	JP7
Serial	Open	Short	Open	Short	Open	Short
Parallel i80	*1	Open	Short	Open	Open	Short
Parallel M68 (default)	*1	Open	Short	Open	Short	Open

<sup>\*1:</sup> JP2 short enables PIN3 as external reset. JP2 open disables reset.

# **Block Diagram**



### **Electrical Characteristics**

Item	Symbol	Condition	Min.	Тур.	Max.	Unit
Operating Temperature Range	Vop		-40	-	+85	°C
Storage Temperature Range	Vst		-50	-	+95	°C
Operating Humidity	Нор		0	•	85	%
Storage Humidity	Hst		0	-	90	%
Vibration	-	10~55Hz	-	-	4	G
Shock	-		-	-	40	G
Supply Voltage	VDD		4.5	5.0	5.5	V
Supply Current (*Note 1)	IDD	Ta=25°C	-	290	435	mA
		VDD=5.0V				
Luminance	L		350	500	-	cd/m²
			102	146	-	ft-L
"H" Level input (*Note 2)	Vih		0.7*VDD	-	-	V
"L" Level input	Vil		-	-	0.3*VDD	V
"H" Level output	Voh		0.8*VDD	-	-	V
"L" Level output	Vol		-	-	0.2*VDD	V

#### Note:

- 1. In-rush current can be approx. 10 times the specified supply current at power up.
- 2. A 10K ohm pull-up resistor is on each input signal for TTL compatibility.

## **Controller Information**

Built-in PT6314 controller.

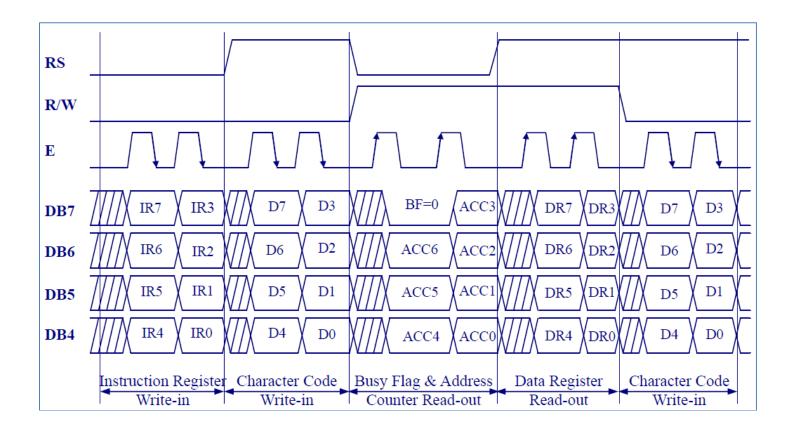
Please download specification at <a href="http://www.newhavendisplay.com/app">http://www.newhavendisplay.com/app</a> notes/PT6314.pdf

# **Table of Commands**

Turkurakiana	Cor	itrol			Ins	structi	on Co	de			Descriptions		
Instructions	RS	R/W	<b>D</b> 7	D6	D5	D4	D3	D2	D1	D0	Descriptions		
Display Clear	0	0	0	0	0	0	0	0	0	1	Clears all display and sets DD-RAM address 0 in address counter.		
Cursor Home	0	0	0	0	0	0	0	0	1	*	Sets DD-RAM address 0 in ACC. Also returns the display being shifted to the original position. DD-RAM contents remain unchanged.		
Entry Mode Set	0	0	0	0	0	0	0	1	I/D	s	Sets the cursor direction and specifies display shift. These operations are performed during writing/reading data.		
Display ON/OFF Control	0	0	0	0	0	0	1	D	С	В	Sets all display ON/OFF (D), cursor ON/OFF (C), cursor blink of character position (B).		
Cursor or Display Shift	or or Display Shift 0 0 0 0 0 1 S/O				S/C	R/L	*	*	Shifts display or cursor, keeping DD-RAM contents.				
Function Set	0	0	0	0	1	IF	N	*	BR1	BR0	Sets data length (IF), number of display lines(N), Set brightness level(BR1,BR0)		
CG-RAM Address Set	0	0	0	1	A	.CG (0	CG-R	AM A	ddres	s)	Sets the CG-RAM address.		
DD-RAM Address Set	0	0	1		ADI	) (DD	-RAN	I Add	ress)		Sets the DD-RAM address.		
Busy Flag and Address Counter Reading	0	1	BF		AC	C (Ad	ldress	Coun	ter)		Reads busy flag (BF) and address counter (ACC).		
Data Writing to CG- or DD-RAM	1	0			C	haract	er Co	de			Writes data into CG-RAM or DD-RAM.		
Data Reading from CG- or DD-RAM	1	1			C	haract	er Co	de			Reads data from CG-RAM or DD-RAM.		
* DD-RAM: Display Data RAM  * CG-RAM: Character Generator RAM  * ACG: CG-RAM Address  * ADD: DD-RAM	* I/D * S = * S =	* I/D = 1: Increment  * I/D = 0: Decrement  * S = 1: Display Shift Enabled  * S = 0: Cursor Shift Enabled  * S/C = 1: Display Shift  * S/C = 0: Cursor Move								* IF = 1: 8-bit Operation * IF = 0: 4-bit Operation * N = 1: 2 Lines Display * N = 0: 1 Line Display * BR1, BR0 = 00: 100%, 01: 75%, 10: 50%, 11: 25%			
Address * ACC: Address Counter		u = 1: u = 0:									* BF = 1: Busy (Internally operating) * BF = 0: Not busy (Instruction acceptable)		

#### **Parallel Interface:**

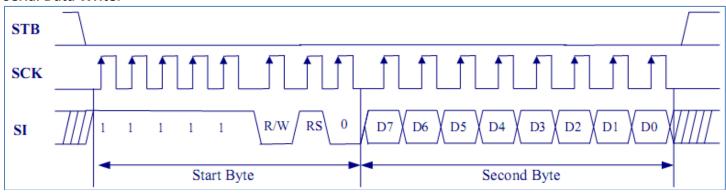
This VFD module can interface in either two 4-bit operations or one 8-bit operation. For 4-bit interface data, only four bus lines (DB4 to DB7) are used for transfer. When to use 4-bit parallel data transfer, DB0 to DB3 keep "H" or "L". The data transfer between the VFD module and the MPU is completed after the 4-bit data has been transferred twice. As for the order of data transfer the four high order bits (for 8-bit operation, DB4 to DB7) are transferred before the four low order bits (for 8-bit operation, DB0 to DB3). The busy flag (BF) are performed before transferring the higher 4 bits. BF checks are not required before transferring the lower 4 bits.



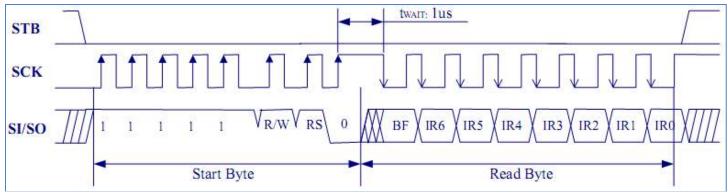
#### **Serial Interface:**

When data is written, it can be inputted when the STB goes to "0". The first byte-Start Byte consists of a total 8 bits including Synchronous bits (bit 1-bit 5), R/W (bit 6), RS (bit 7) and bit 8. The register is selected (IR or DR) by RS(bit 7) while data write or read is selected by R/W (bit 6 = 00). Next 8-bit instruction byte will follow closely after the defined operation in Start Byte. Data should be keep active in rising edge of clock while it would be output in falling edge in Read operation. Follow the protocol herein:

#### **Serial Data Write:**

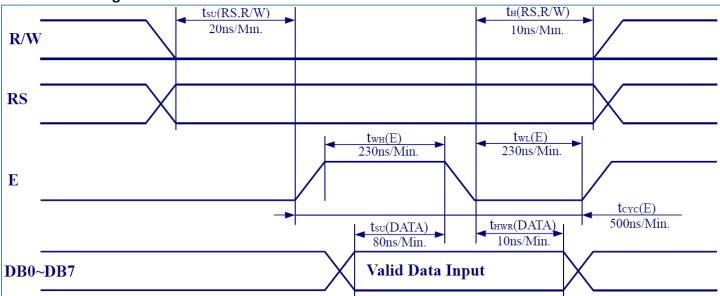


#### **Serial Data Read:**

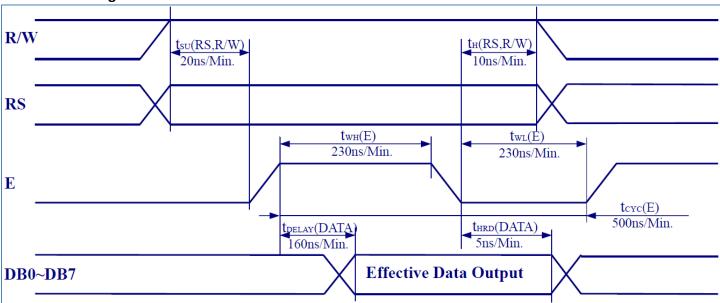


# **Timing Characteristics:**

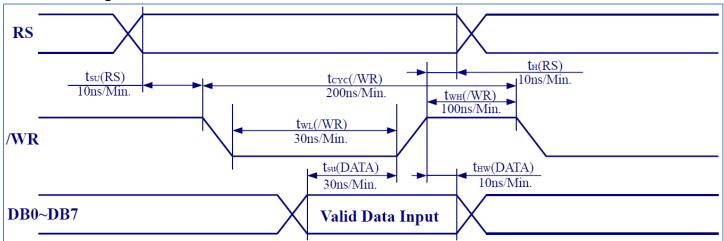
#### M68 Write Timing:



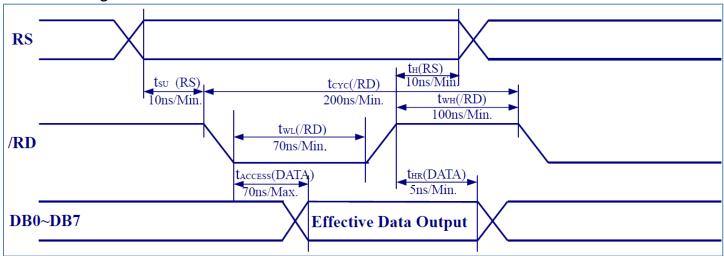
## M68 Read Timing:



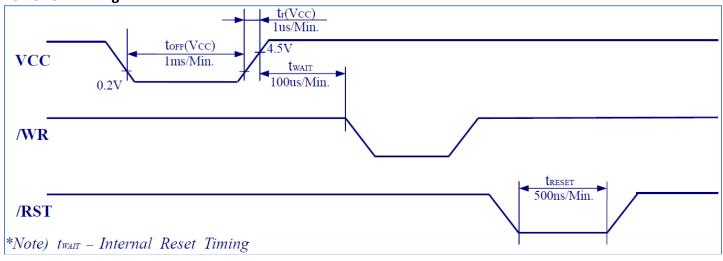
#### i80 Write Timing:



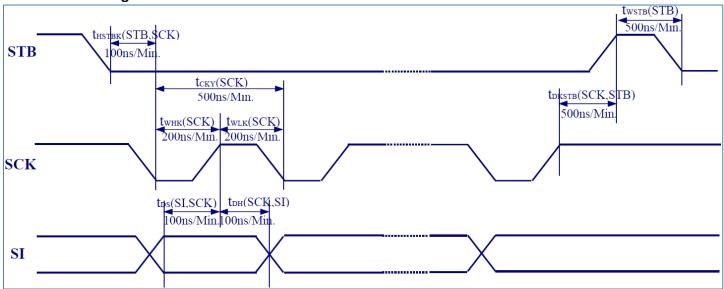
#### i80 Read Timing:



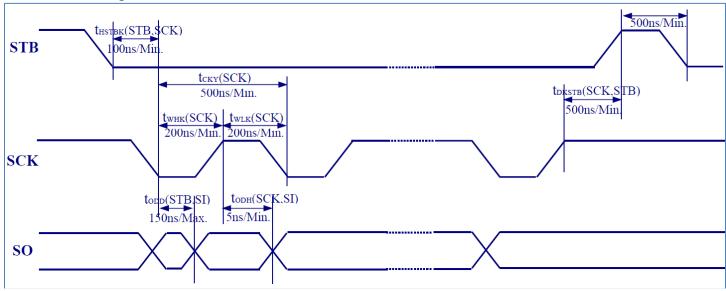
#### **Power ON Timing:**



#### **Serial Write Timing:**



#### **Serial Read Timing:**



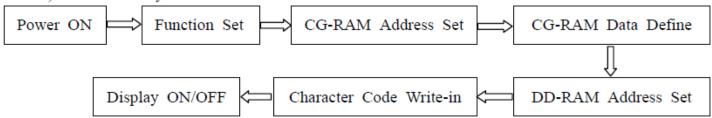
# **Built-in Font Table**

	è	I	pper	D7	0	0	0	0	0	0	0	0	1	1	1	1	1	1	1	1
1	1		bble		0	0	0	0	1	1	1	1	0	0	0	0	1	1	i	1
Lov	wer	1		D5	0	0	1	1	0	0	1	1	0	0	1	1	0	0	1	1
	ble		/	D4	0	1	0	1	0	1	0	1	0	1	0	1	0	1	0	1
D3	D2	D	Do		0	1	2	3	4	5	6	7	8	9	A	В	C	D	E	F
0	0	0	0	0	CG-RAM (∦1)										11111		-::			
0	0	0	1	1	CG-RAM	I										F	-			
0	0	1	0	2	CG-RAM (∦3)		11	2				•				•1	ij			
0	0	1	1	3	CG-RAM (#4)		#				<u></u>									
0	1	0	0	4	CG−RAM (#5)		-					1.						17		
0	1	0	1	5	CG-RAM (#6)		<b>!</b>					1				7	#		Œ	
0	1	1	0	6	CG-RAM (#7)						#	1,,1		-#-						
0	1	1	1	7	CG−RAM (#8)			ľ												
1	0	0	0	8	CG-RAM (#1)		ĸ.			X		×			4	•]]	-		J	
1	0	0	1	9	CG-RAM (#2)		Ì			H	1					T				•
1	0	1	0	A	CG-RAM (#3)		#								11.		Ĥ	1.		
1	0	1	1	В	CG-RAM (#4)	1	-#-				K	1			<b>#</b>	#	-			
1	1	0	0	С	CG-RAM (#5)	****										=.1			•	
1	1	0	1	D	CG-RAM (#6)	•	:::::: ::::::	******					#		***		••••		#	
1	1	1	0	E	CG-RAM (#7)	•					m									
1	1	1	1	F	CG-RAM (#8)	<b></b>	×	7								٠.,١	7,7			

# **Example Initialization Sequence**

RS	R/W	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0	Description
	Power ON							Wait for 100 us		
0	0	0	0	1	1	1	*	0	0	Function set: - Data length: 8 bits - Display line No.: 2 lines - Brightness: 100%
0	0	0	1	0	0	0	0	0	0	CG-RAM address set to 00H
		*	*	*	D	D	D	D	D	
1	0	*	*	*	D	D	D	D	D	Writes data into CG-RAM (the user-definable characters)
1	0									64 bytes in total (8 characters)
		*	*	*	D	D	D	D	D	
0	0	1	0	0	0	0	0	0	0	DD-RAM address set to 00H (the first column of upper line)
		D	D	D	D	D	D	D	D	With the interpolation
1	0	D	D	D	D	D	D	D	D	Writes data into DD-RAM (choose the character codes to display in upper line)
1										Totally 20 bytes in the upper line (20 characters)
		D	D	D	D	D	D	D	D	orani, or cytosis are approximately
0	0	1	1	0	0	0	0	0	0	DD-RAM address set to 40H (the first column of lower line)
		D	D	D	D	D	D	D	D	Writer data into DD DAM (shapes the character ander to
1	0	D	D	D	D	D	D	D	D	Writes data into DD-RAM (choose the character codes to display in lower line)
1										Totally 20 bytes in the lower line (20 characters)
		D	D	D	D	D	D	D	D	
0	0	0	0	0	0	1	1	0	0	Display ON, Cursor OFF, Cursor blink OFF

\*Note): D is the binary data to be written-in.



# **Quality Information**

Test Item	Content of Test	Test Condition	Note
High Temperature storage	Endurance test applying the high	+80°C , 48hrs	2
	storage temperature for a long time.		
Low Temperature storage	Endurance test applying the low storage	-30°C , 48hrs	1,2
	temperature for a long time.		
High Temperature	Endurance test applying the electric stress	+70°C 48hrs	2
Operation	(voltage & current) and the high thermal		
	stress for a long time.		
Low Temperature	Endurance test applying the electric stress	-20°C , 48hrs	1,2
Operation	(voltage & current) and the low thermal		
	stress for a long time.		
High Temperature /	Endurance test applying the electric stress	+40°C, 90% RH, 48hrs	1,2
Humidity Operation	(voltage & current) and the high thermal		
	with high humidity stress for a long time.		
Thermal Shock resistance	Endurance test applying the electric stress	0°C,30min -> +25°C,5min ->	
	(voltage & current) during a cycle of low	+50°C,30min = 1 cycle	
	and high thermal stress.	10 cycles	
Vibration test	Endurance test applying vibration to	10-55Hz , 15mm amplitude.	3
	simulate transportation and use.	60 sec in each of 3 directions	
		X,Y,Z	
		For 15 minutes	
Static electricity test	Endurance test applying electric static	VS=800V, RS=1.5kΩ, CS=100pF	
	discharge.	One time	

Note 1: No condensation to be observed.

Note 2: Conducted after 4 hours of storage at 25°C, 0%RH.

**Note 3:** Test performed on product itself, not inside a container.

## **Precautions for using LCDs/LCMs**

See Precautions at www.newhavendisplay.com/specs/precautions.pdf

## **Warranty Information and Terms & Conditions**

http://www.newhavendisplay.com/index.php?main\_page=terms